NSN 5961-01-406-5929

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view Online at https://aerobasegroup.com/hsh/5961-01-406-5929
Inclosure Material:
Ceramic
Overall Length:
Between 0.215 inches and 0.225 inches
Overall Height:
Between 0.061 inches and 0.075 inches
Overall Width:
Between 0.145 inches and 0.155 inches
Internal Configuration:
Junction contact
Mounting Method:
Compression
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
600.00 milliamperes source cutoff current
Power Rating Per Characteristic:
1.16 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Test Data Document:
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
4 printed circuit
Specification Data:
81349-mil-prf-19500/291 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0
Mil-std (military Standard):

Mil-prf-19500 spec.